NSN 5961-00-855-2792

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-855-2792 **Inclosure Material:** Metal **Overall Length:** 0.428 inches **Overall Diameter:** 0.350 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -50.0 collector to emitter voltage, dc and -50.0 collector to base voltage, dc and -20.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No